# NSN 5961-01-012-6680

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Inclosure Material:

Metal

**Overall Length:** 

1.530 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

Features Provided:

### Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

160.0 breakdown voltage, collector-to-base, emitter open and 7.0 breakdown voltage, collector-to-emitter, base open and 140.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

16.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn.

#### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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